

Device Features

- OIP3 = 37.6 dBm @ 1550 MHz
- Gain = 19.5 dB @ 1550 MHz
- Output P1 = 21.5 dBm @1550 MHz
- N.F = 1.1 dB @ 1550MHz
- Patented temperature compensation
- Lead-free/RoHS-compliant SOT-89 SMT package

Product Description

BeRex's BNT02 is a high performance GaAs E-pHEMT amplifier is internally matched to 75 Ohms and uses a patented **temperature compensation** circuit to provide stable current over the operating temperature range without the need for external components. The BNT02 is designed for high linearity & low noise figure in a wideband of 45-2200MHz. It is packaged in a RoHS-compliant SOT-89 surface mount package and design in set-top infrastructure projects for 75ohm CATV and satellite applications.

Applications

- Set-Top Box
- Satellite & Drop Amplifier
- FTTH Receiver / Optical Transmitter
- RFoG / MOCA

Applications Circuit

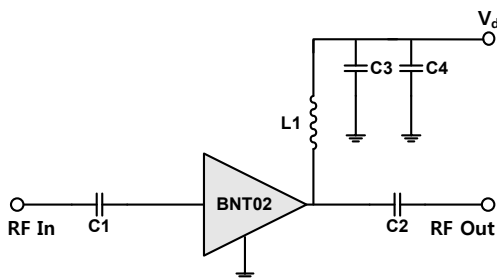


Figure 1 Applications Circuit

Package Type



SOT-89 SMT Package
Figure 2 Package Type

Typical Performance¹

Parameter	Frequency						Unit
	100 ²	300 ²	800 ²	950	1550	2150	
Vd = 5V							MHz
Gain	20.9	20.7	20.1	20.3	19.5	18.2	dB
S11	-12.4	-14.7	-21.1	-12.8	-14.2	-12.5	dB
S22	-10.7	-11.5	-18.5	-16.9	-20.4	-15.0	dB
OIP3 ³	38.9	41.1	38.2	38.5	37.6	39.8	dBm
P1dB	21.5	21.6	21.4	21.5	21.5	21.0	dBm
NF	0.9	0.9	1.1	1.2	1.1	1.2	dB
CTB ⁴	74.0	74.0	76.0	-	-	-	dBc
CSO ⁴	61.0	63.0	61.5	-	-	-	dBc
Vd = 3.3V							MHz
Gain	20.6	20.3	19.6	19.8	18.9	17.6	dB
S11	-13.4	-16.5	-20.3	-12.8	-12.7	-11.2	dB
S22	-11.7	-12.8	-17.8	-19.5	-17.7	-13.8	dB
OIP3 ³	35.1	34.5	31.0	32.6	31.9	30.7	dBm
P1dB	17.8	18.1	17.5	17.7	17.6	17.1	dBm
NF	0.9	0.9	1.1	1.2	1.1	1.2	dB

¹ Device performance _ measured on a BeRex evaluation board at 25°C, 75 Ω system.

² 45 to 800MHz. Value were measured with IF Band tuned.

³ OIP3 _ measured with two tones at an output of 5dBm per tone separated by 1 MHz.

⁴ CTB/CSO _ measured in 101 channels, 23dBmV/channel flat loading conditions.

Parameter	Min.	Typical	Max.	Unit
I _d @ (V _d = 5V)	76	85	93	mA
I _d @ (V _d = 3.3V)	43	48	53	mA
dG/dT		0.006		dB/°C
R _{TH}		49.4		°C/W

Absolute Maximum Ratings

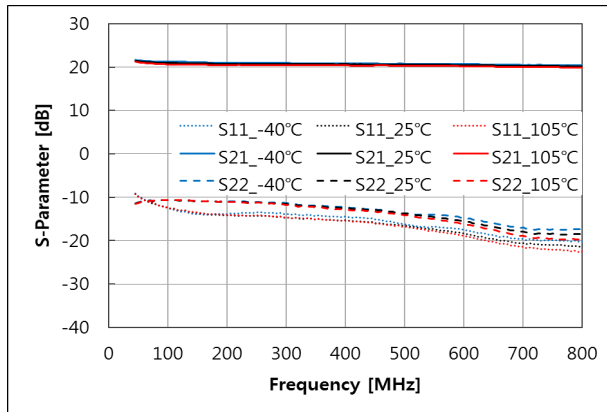
Parameter	Rating	Unit
Operating Case Temperature	-40 to +105	°C
Storage Temperature	-55 to +155	°C
Junction Temperature	+220	°C
Operating Voltage	+7.0	V
Supply Current	190	mA
Input RF Power	20	dBm

Operation of this device above any of these parameters may result in permanent damage.

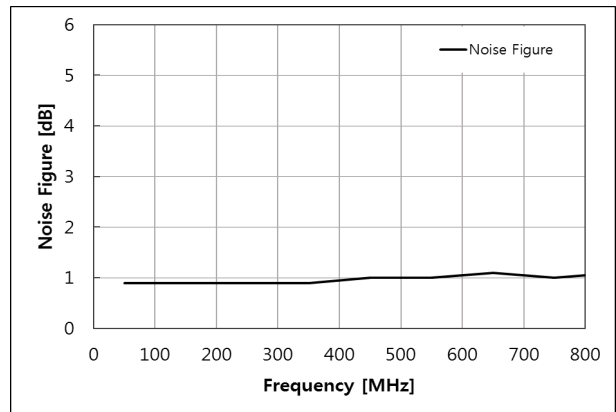
Typical Performances @45MHz - 800MHz

Typical conditions are at $V_d = 5V$, $T = 25^\circ C$, $Z_L = 75\Omega$, unless otherwise noted.

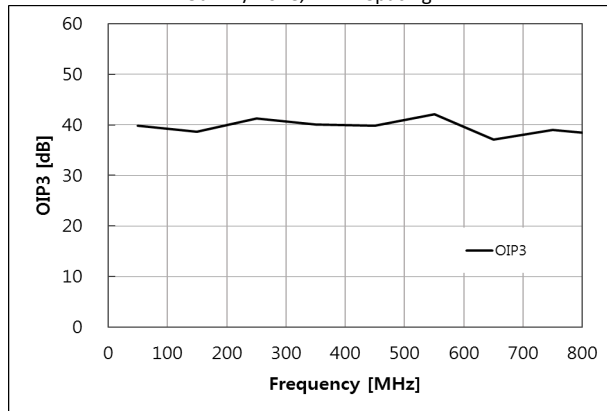
S-parameters vs. Temp



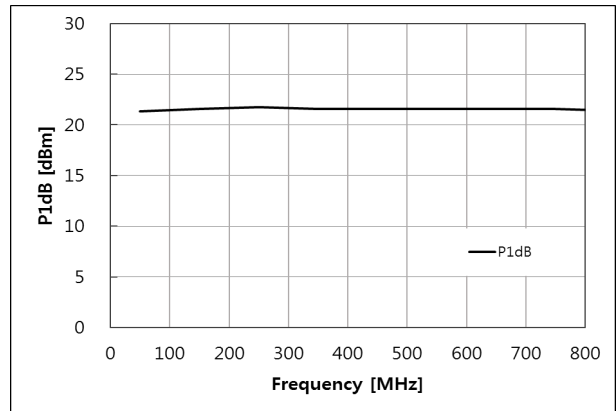
Noise Figure vs. Frequency



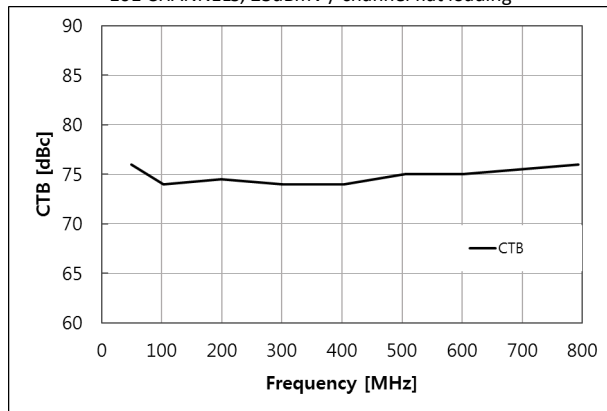
OIP3 vs. Frequency
5dBm / Tone, 1MHz Spacing



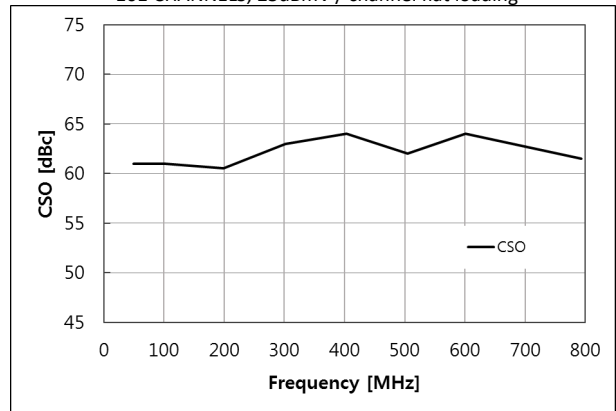
P1dB vs. Frequency



CTB vs. Frequency
101 CHANNELS, 23dBmV / channel flat loading



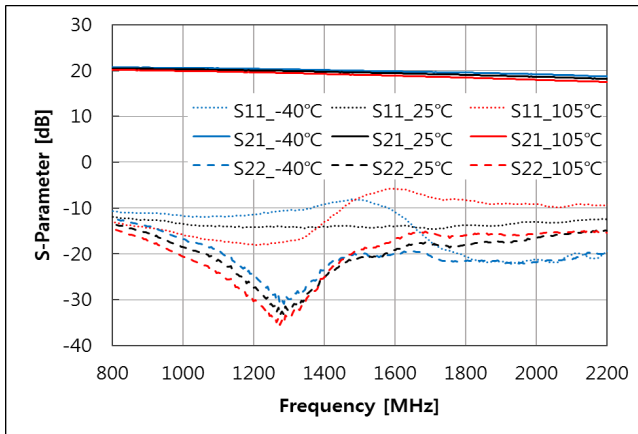
CSO vs. Frequency
101 CHANNELS, 23dBmV / channel flat loading



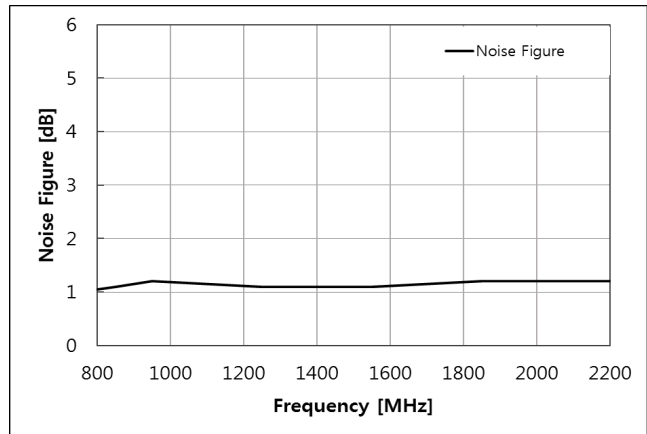
Typical Performances @800MHz - 2200MHz

Typical conditions are at $V_d = 5V$, $T = 25^\circ C$, $Z_L = 75\Omega$, unless otherwise noted.

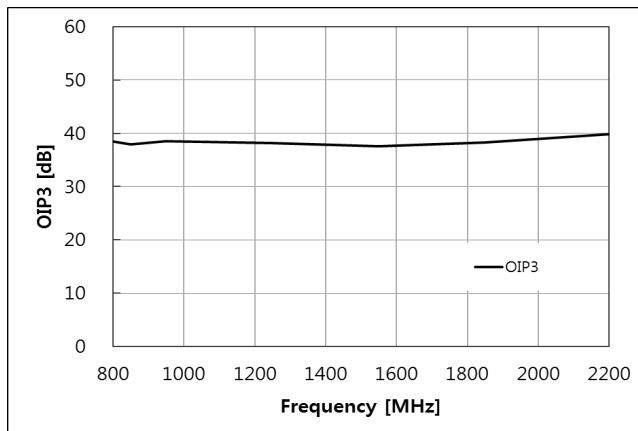
S-parameters vs. Temp



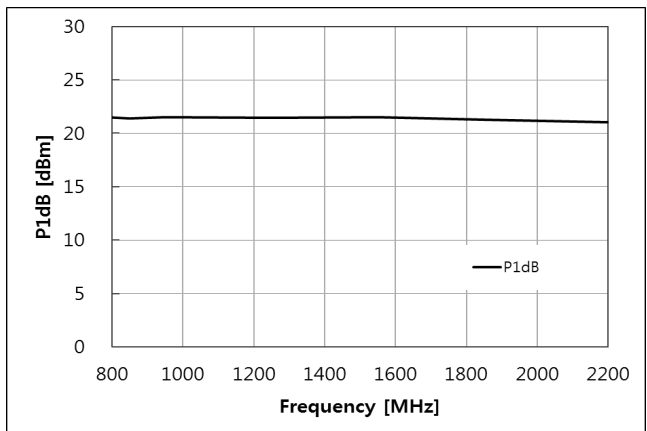
Noise Figure vs. Frequency



OIP3 vs. Frequency
5dBm / Tone, 1MHz Spacing



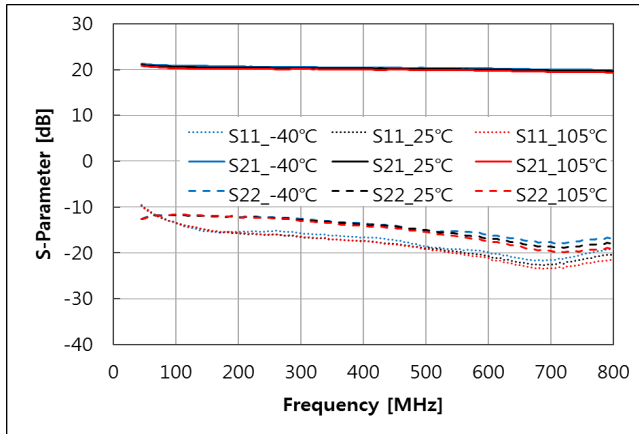
P1dB vs. Frequency



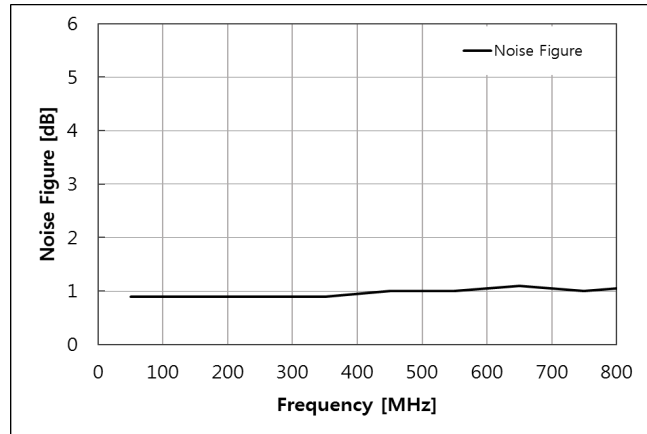
Typical Performances @45MHz - 800MHz

Typical conditions are at $V_d = 3.3V$, $T = 25^\circ C$, $Z_L = 75\Omega$, unless otherwise noted.

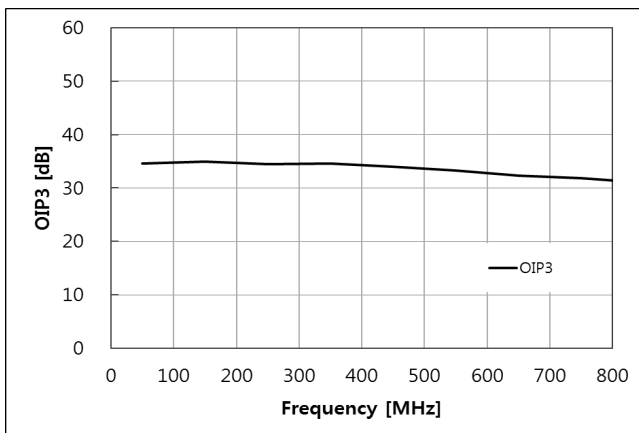
S-parameters vs. Temp



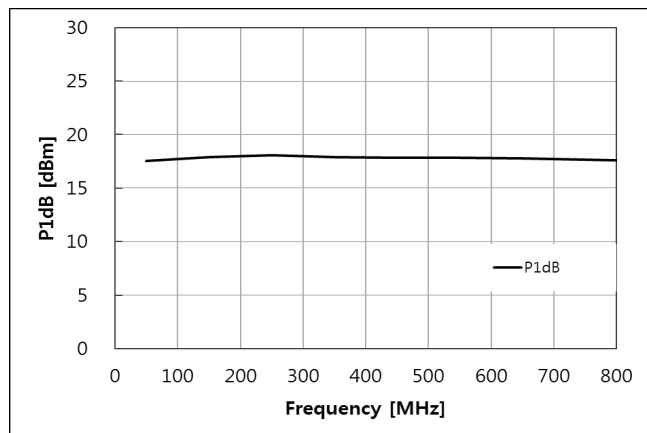
Noise Figure vs. Frequency



OIP3 vs. Frequency
5dBm / Tone, 1MHz Spacing

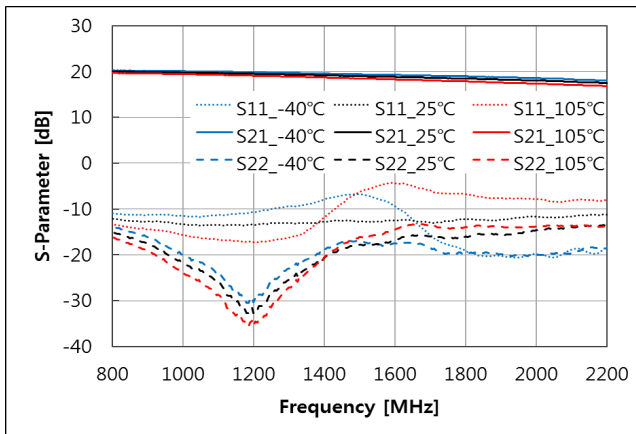
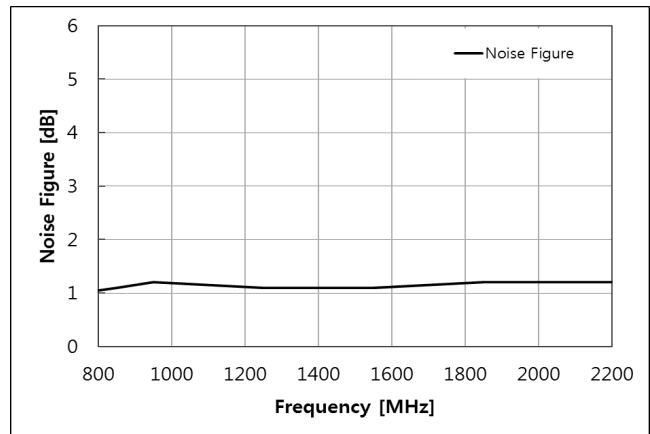
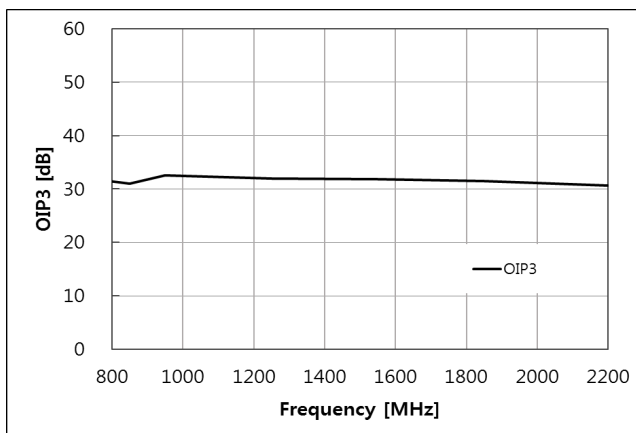
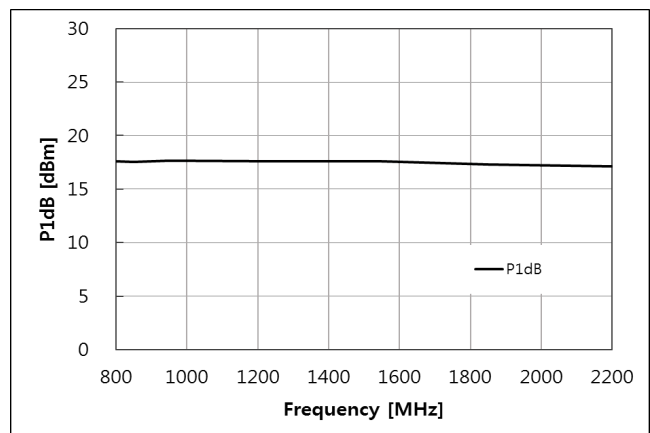


P1dB vs. Frequency

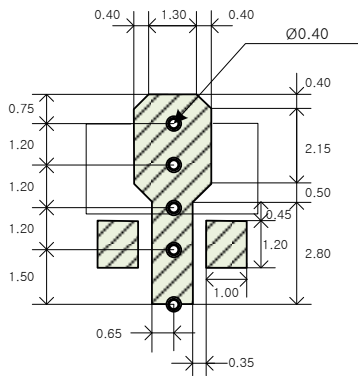


Typical Performances @800MHz - 2200MHz

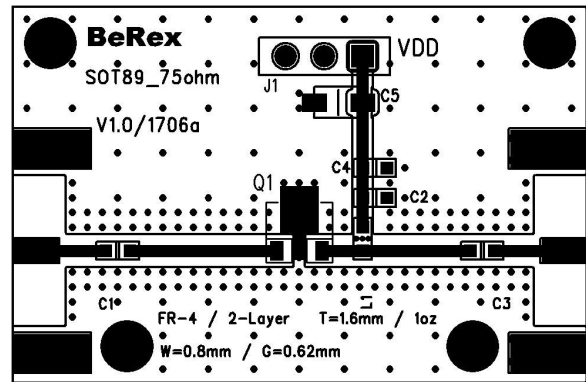
 Typical conditions are at $V_d = 3.3V$, $T = 25^\circ C$, $Z_L = 75\Omega$, unless otherwise noted.

S-parameters vs. Temp

Noise Figure vs. Frequency

OIP3 vs. Frequency
 5dBm / Tone, 1MHz Spacing

P1dB vs. Frequency


Suggested PCB Land Pattern and PAD Layout

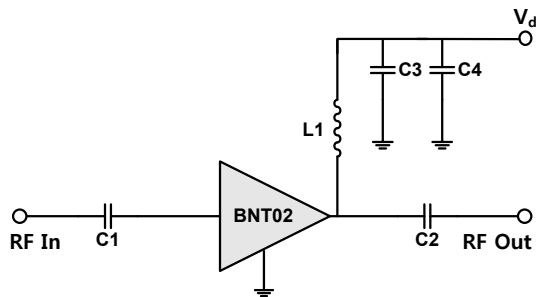
PCB Land Pattern


Note : All dimension _ millimeters

PCB Mounting


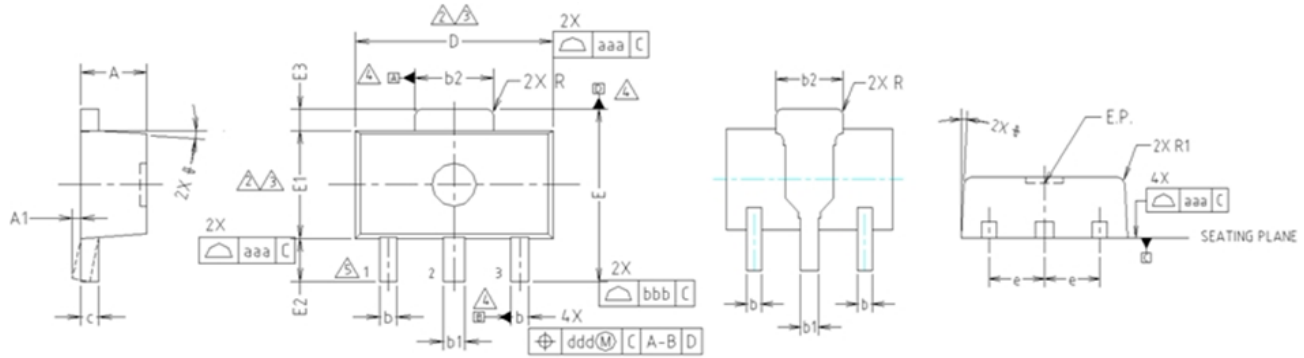
Note : PCB lay out _ on BeRex website

Applications Circuit and Bill of Material

Applications Circuit

Bill of Material

No	Ref Des	Qty	Part Number	Remark
1	C1,C2	1	CAP 1608 100pF	800 to 2200MHz
		1	CAP 1608 1nF	45 to 800MHz
2	C3	1	CAP 1608 100pF	
3	C4	1	CAP 1608 1uF	
4	L1	1	IND 1608 39nH	800 to 2200MHz
		1	IND 1608 560nH	45 to 800MHz
5	J1	1	3 Pin Header	
6	RF in, RF out	2	F Type_END_LAUNCH	
7	Q1	1	BNT02	SOT-89

Package Outline Dimension



NOTE:
1. DIMENSIONS IN MILLIMETERS.

△ DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.5mm PER END. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.5mm PER SIDE.

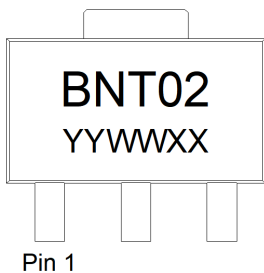
△ DIMENSIONS D AND E1 ARE DETERMINED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

△ DATUMS A, B AND D TO BE DETERMINED 0.18mm FROM THE LEAD TIP.

△ TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	1.40	1.50	1.60	
A1	0.00	—	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
c	0.40	0.42	0.46	
D	4.40	4.50	4.70	2,3
E	3.70	4.00	4.30	
E1	2.40	2.50	2.70	2,3
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
e	1.50 TYP.			
φ	4° TYP.			
R	0.15 TYP.			
R1	—	—	0.20	
SYMBOL	TOLERANCES OF FORM AND POSITION	NOTE		
aaa	0.15			
bbb	0.20			
ccc	0.10			
ddd	0.10			

Package Marking

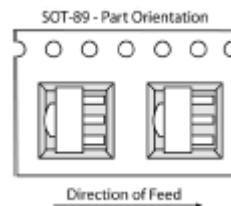


YY = Year, WW = Working Week,
XX = Wafer No.

Tape & Reel

SOT89

Packaging information:



Tape Width (mm): 12
Reel Size (inches): 7
Device Cavity Pitch (mm): 8
Devices Per Reel: 1000

Lead plating finish

100% Tin Matte finish

(All BeRex products undergoes a 1 hour, 150 degree C, Anneal bake to eliminate thin whisker growth concerns.)

MSL / ESD Rating

ESD Rating:	Class 1C
Value:	Passes <2000V
Test:	Human Body Model (HBM)
Standard:	JEDEC Standard JESD22-A114B
MSL Rating:	Level 1 at +265°C convection reflow
Standard:	JEDEC Standard J-STD-020



Proper ESD procedures should be followed when handling this device.

NATO CAGE code:

2	N	9	6	F
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